

STPS640C-Y

Datasheet - production data

Automotive power Schottky rectifier

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Features

- Low forward voltage drop
- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Low thermal resistance
- AEC-Q101 qualified.

Description

This dual Schottky rectifier is designed for switch mode power supplies and other power converters.

This device is intended for use in low and medium voltage operation, and in particular high frequency circuits where low switching losses are required (free wheeling and polarity protection) in automotive applications.

| Symbol | Value |
|----------------------|---------|
| I _{F(AV)} | 2 x 3 A |
| V _{RRM} | 40 V |
| Тj | 150 °C |
| V _{F (Typ)} | 0.50 V |
| | |

Table 1. Device summary

DocID025068 Rev 2

This is information on a product in full production.

1 Characteristics

| Symbol | Parameter | | | Unit |
|---------------------|--|------------|-------|------|
| V _{RRM} | Repetitive peak reverse voltage | | 40 | V |
| I _{F(RMS)} | Forward rms current | | 6 | А |
| | Average forward current, $\delta = 0.5$, T _c = 135 °C | per diode | 3 | А |
| I _{F(AV)} | Average forward current, $0 = 0.5$, $T_c = 155$ C | per device | 6 | A |
| I _{FSM} | Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}, T_c = 25 \text{ °C}$ | | °C 75 | А |
| I _{RRM} | Peak repetitive reverse current $t_p = 2 \ \mu s, F = 1 \text{kHz}$ | | 1 | А |
| P _{ARM} | Repetitive peak avalanche power $t_p = 1 \ \mu s, T_c = 25 \ ^{\circ}C$ | | 1300 | W |
| T _{stg} | Storage temperature range | | | °C |
| Тј | Operating junction temperature | | | °C |

Table 2. Absolute ratings (limiting values, per diode)

Table 3. Thermal parameters

| Symbol | Parameter | Value | Unit | |
|------------------------------|------------------|--------|------|------|
| P | Junction to case | diode | 5.5 | |
| R _{th(j-c)} Junctio | | device | 3 | °C/W |
| R _{th(c)} | coupling | | 0.5 | |

When the diodes 1 and 2 are used simultaneously : Δ Tj(diode 1) = P(diode1) x R_{th(j-c)}(Per diode) + P(diode 2) x R_{th(c)}

| Symbol | Parameter | Test conditions | | Min. | Тур | Max. | Unit |
|---|-------------------------|-----------------------------------|----------------------|------|------|------|------|
| I _R ⁽¹⁾ Reverse leakage current | Deverse leekege ourrent | T _j = 25 °C | V V | - | - | 100 | μA |
| | T _j = 125 °C | V _R = V _{RRM} | - | 2 | 10 | mA | |
| V _F ⁽²⁾ Forward voltage drop | T _j = 25 °C | 1 2 4 | - | - | 0.63 | | |
| | Forward voltage drep | T _j = 125 °C | I _F = 3 A | - | 0.50 | 0.57 | V |
| | Folward voltage diop | T _j = 25 °C | I _F = 6 A | - | - | 0.84 | |
| | | T _j = 125 °C | | - | 0.67 | 0.72 | |

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: t_p = 380 µs, δ < 2%

To evaluate the conduction losses use the following equation: P = 0.42 x $I_{F(AV)}$ + 0.050 x ${I_F}^2_{(RMS)}$



Figure 1. Average forward power dissipation versus average forward current (per diode)

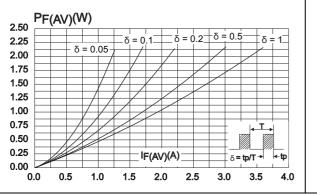


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

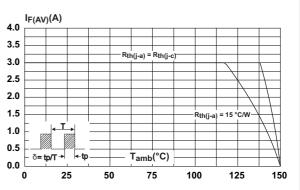


Figure 3. Normalized avalanche power derating Figure 4. Normalized avalanche power derating versus pulse duration

versus junction temperature

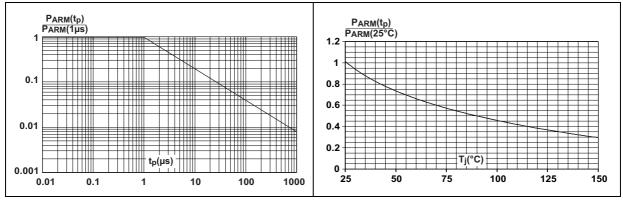


Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

Figure 6. Reverse leakage current vs. reverse voltage applied (typical values, per diode)

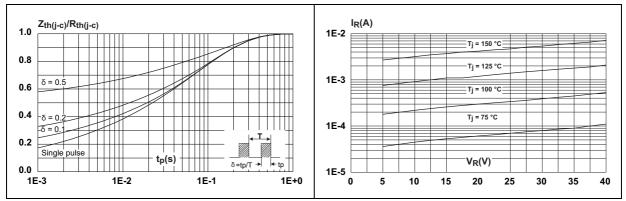
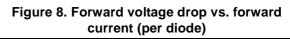


Figure 7. Junction capacitance vs. reverse voltage applied (typical values, per diode)



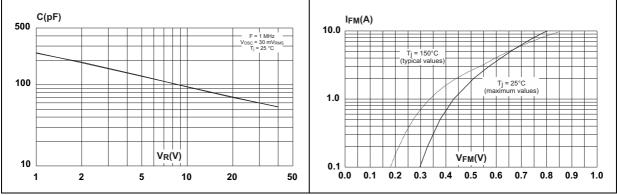
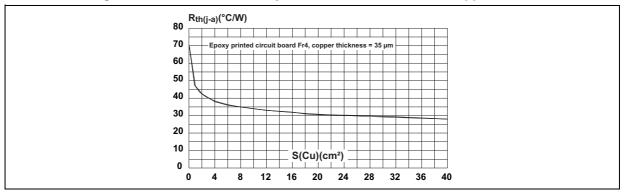


Figure 9. Thermal resistance junction to ambient versus copper surface under tab

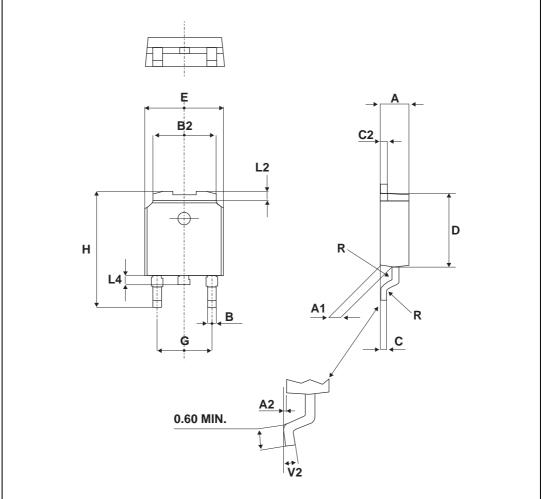


2 Package information

- Epoxy meets UL94,V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK[®] is an ST trademark.



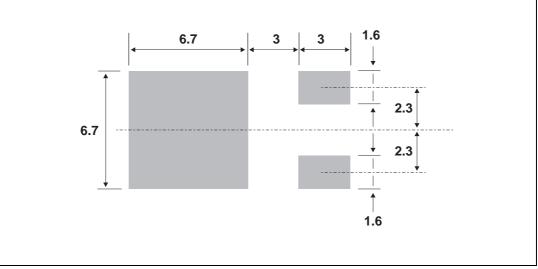




| | Dimensions | | | | | |
|------|------------|-------------|-------|-------|------------|-------|
| Ref. | | Millimeters | | | Inches | |
| | Min. | Тур. | Max. | Min. | Тур. | Max. |
| А | 2.20 | | 2.40 | 0.086 | | 0.094 |
| A1 | 0.90 | | 1.10 | 0.035 | | 0.043 |
| A2 | 0.03 | | 0.23 | 0.001 | | 0.009 |
| В | 0.64 | | 0.90 | 0.025 | | 0.035 |
| B2 | 5.20 | | 5.40 | 0.204 | | 0.212 |
| С | 0.45 | | 0.60 | 0.017 | | 0.023 |
| C2 | 0.48 | | 0.60 | 0.018 | | 0.023 |
| D | 6.00 | | 6.20 | 0.236 | | 0.244 |
| Е | 6.40 | | 6.60 | 0.251 | | 0.259 |
| G | 4.40 | | 4.60 | 0.173 | | 0.181 |
| Н | 9.35 | | 10.10 | 0.368 | | 0.397 |
| L2 | | 0.80 typ. | | | 0.031 typ. | |
| L4 | 0.60 | | 1.00 | 0.023 | | 0.039 |
| V2 | 0° | | 8° | 0° | | 8° |

Table 5. DPAK dimension values

Figure 11. Footprint dimensions in mm (inches)





3 Ordering information

| Order code | Marking | Package | ackage Weight Bas | | Delivery mode | |
|---------------|-----------|---------|-------------------|------|---------------|--|
| STPS640CBY-TR | STPS640CY | DPAK | 0.3 g | 2500 | Tape and reel | |

4 Revision history

Table 7. Revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 6-Nov-2013 | 1 | First issue |
| 04-Dec-2013 | 2 | Properties changed from preliminary data to production data. |



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